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SJ

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Gallium arsenide epitaxy wafers

砷化镓外延片

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What this standard covers

This standard specifies the GaAs epitaxial wafers and liquid vapor phase epitaxial wafers grade nomenclature, technical requirements, test methods, inspection rules, marking, packaging, transport and storage. This standard applies to the preparation of a field-effect transistor, varactor. Geng China Hall devices and devices using gallium arsenide wafer.

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Standards quoted by this document

SJ 3244.1; SJ 3247; SJ 3244.4; SJ 3244.3; GB 6624; GB 2828